7D5	
rev	

	Туре	L#	Hits	Search Text	DBs	Time	Comme	Error Definition	Er
1	BRS	L1	112	" 5062133"	JPO; DER	2004/01/2 6 07:40	nts		0
2	BRS	L2	32	"5208848"	WEN T; USP AT; US-P GPU B; EPO; JPO; DER WEN T;	2004/01/2 6 07:40			0
3	BRS	L3	162	" 5351276"	USP AT; US-P GPU B; EPO; JPO; DER WEN T;	2004/01/2 6 07:40			0
4	BRS	L4	10	"5386459"	EPO; JPO; DER WEN T;	2004/01/2 6 07:41			0
5	BRS	L5	19	"5390241"	EPO; JPO; DER WEN T;	2004/01/2 6 07:41			0
6	BRS	L6	49	"5392345"	JPO; DER WEN T;	2004/01/2 6 07:41			0
7	BRS	L7	23	"5404400"	USP AT; US-P GPU B; EPO; JPO; DER WEN T;	2004/01/2 6 07:41			0
8	BRS	L8	52	"5459780"	JPO; DER WEN T;	2004/01/2 6 07:41			o
9	BRS	L9	17	"5463685"	JPO; DER WEN T;	2004/01/2 6 07:41			0
10	BRS	L10	30	"5682386"	USP AT; US-P GPU B; EPO; JPO; DER WEN T;	2004/01/2 6 07:41			0

	Туре	L#	Hits	Search Text	DBs	Time Stamp	Comme nts	Error Definition	E
11	BRS	L11	85	"5689553"	USP; P GPU O; DER BEPO; DER DER VEN	2004/01/2 6 07:41			0
12	BRS	L12	3	"5977698"	USP AT; US-P GPU B;	2004/01/2 6 07:42			0
13	BRS	L13	8	"6128293"	USP AT; US-P GPU B;	2004/01/2 6 07:42			0
14	BRS	L14	24	"5536193"	USP AT; US-P GPU B; EPO; JPO; DER WEN T;	2004/01/2 6 07:42			0
15	BRS	L15	10	"5852303"	USP AT; US-P GPU B; EPO; JPO; DER WEN T;	2004/01/2 6 07:42			0
16	BRS	L16	9	"6181056"	USP AT; US-P GPU B; EPO; JPO; DER WEN T;	2004/01/2 6 07:42			0
17	BRS	L 17	5	"6218771"	USP AT; US-P GPU B; EPO; JPO; DER WEN T;	2004/01/2 6 07:42			0
18	BRS	L18	6	"6459096"	USP AT; US-P GPU B; EPO; JPO; DER WEN T;	2004/01/2 6 07:42			0
19	BRS	L19	594	1 or 2 or 3 or 4 or 5 or 6 or 7 or 8 or 9 or 10 or 11 or 12 or 13 or 14 or 15 or 16 or 17 or 18	B; EPO; JPO; DER WEN T;	2004/01/2 6 07:43			О
20	BRS	L20	8	19 and (DRAM)	USP AT; US-P GPU B; EPO; JPO; DER WEN T;	2004/01/2 6 07:44			0

	Type	L#	Hits	Search Text	DBs	Time Stamp	Comme nts	Error Definition	Er
21	BRS	L21	43	19 and capacitor	USP AT; US-P GPU B; EPO; JPO; DER WEN T;	2004/01/2 6 07:44			0
22	BRS	L22	4	21 and dielectric	USP AT; US-P GPU B; EPO; JPO; DER WEN T;	2004/01/2 6 07:44			0
23	BRS	L23	66	19 and (capacitor or dielectric)	USP AT; US-P GPU B;	2004/01/2 6 07:45			0
24	BRS	L24	3	23 and (AIN or (aluminum adj1 nitride))		2004/01/2 6 07:45			0
25	BRS	L25	2	24 and amorphous	USP AT; US-P GPU B; EPO; JPO; DER WEN T;	2004/01/2 6 07:45			О
26	BRS	L26	2	25 and (oxid\$3 or oxyg\$4)	USP AT; US-P GPU B; EPO; JPO; DER WEN T;	2004/01/2 6 07:45			0